

MOS FET Relays

G3VM-101LR

World's Smallest SSOP Package MOS FET Relays with High Load Voltage of 100 V.

- Leakage current of 200 pA max. when output relay is open.
- Information correct as of May 2007, according to data obtained by OMRON.

RoHS compliant

♠ Refer to "Common Precautions".

■ Application Examples

- Semiconductor inspection tools
- · Measurement devices
- Broadband systems
- Data loggers



Note: The actual product is marked differently from the image

shown here.

■ List of Models

Contact form	Terminals	Load voltage (peak value) Model		Load voltage (peak value) Model Minimum p		Minimum packaging unit
				Number per tape		
SPST-NO	Surface-mounting	100 VAC	G3VM-101LR			
	terminals		G3VM-101LR (TR)	1,500		

■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-101LR



Note: A tolerance of ± 0.1 mm applies to all dimensions unless otherwise

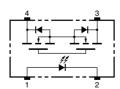
specified.

Weight: 0.03 g

Note: The actual product is marked differently from the image shown here.

■ Terminal Arrangement/Internal Connections (Top View)

G3VM-101LR



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-101LR



Note:

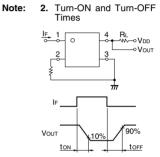
■ Absolute Maximum Ratings (Ta = 25°C)

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Item		Symbol	ol Rating Un		Measurement Conditions			
Input	LED forward current	I _F	50	mA				
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C			
	LED reverse voltage	V_R	5	V				
	Connection temperature	Tj	125	°C				
Output	Output dielectric strength	V _{OFF}	100	V				
	Continuous load current	Io	80	mA				
	ON current reduction rate	Δ I _O /°C	-0.8	mA/°C	Ta ≥ 25°C			
	Connection temperature	Tj	125	°C				
	ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min			
Ambient operating temperature		Ta	-20 to +85	°C	With no icing or condensation			
Storage temperature		T _{stg}	-40 to +125	°C	With no icing or condensation			
Soldering temperature			260	°C	10 s			

The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

Item		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA V _R = 5 V	
	Reverse current	I _R			10	μΑ		
	Capacity between terminals	C _T		15		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I _{FT}		1	5	mA	I _O = 80 mA	
Output	Maximum resistance with output ON	R _{ON}		8	14	Ω	I _F = 10 mA, I _O = 80 mA, t = 10 ms	
	Current leakage when the relay is open	I _{LEAK}			200	pA	V _{OFF} = 80 V	
	Capacity between terminals	C _{OFF}		6	8	pF	V = 0, f = 100 MHz, t < 1 s	
Capacity between I/O terminals		C _{I-O}		0.6		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance between I/O terminals		R _{I-O}	1,000			ΜΩ	V _{I-O} = 500 VDC, RoH ≤ 60%	
Turn-ON time		tON		0.1	0.3	ms	$I_F = 5$ mA, $R_L = 200 \Omega$,	
Turn-OFF time		tOFF		0.1	0.3	ms	V _{DD} = 20 V (See note 2.)	



■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit	
Output dielectric strength	V _{DD}			80	V	
Operating LED forward current	I _F	10		30	mA	
Continuous load current	Io			80	mA	
Operating temperature	Ta	25		60	°C	

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-101LR

■ Safety Precautions

Refer to "Common Precautions" for all G3VM models.